

FAN4174 / FAN4274 Single and Dual, Rail-to-Rail VO, CMOS Amplifier

Features

- 200 µA Supply Current per Amplifier
- 3.7 MHz Bandwidth
- Output Swing to Within 10 mV of Either Rail
- Input Voltage Range Exceeds the Rails
- 3 V / µs Slew Rate
- 25 nV / √Hz Input Voltage Noise
- Replaces KM4170 and KM4270
- FAN4174 Competes with OPA340 and TLV2461; Available in a SOT23-5 Package
- FAN4274 Competes with OPA2340 and TLV2462; Available in MSOP-8 Package
- Fully Specified at +5 V Supplies

Applications

- Motor Control
- Portable / Battery-pow ered Applications
- PCMCIA, USB
- Mobile Communications, Cellular Phones, Pagers
- Notebooks and PDAs
- Sensor Interface
- A/D Buffer
- Active Filters
- Signal Conditioning
- Portable Test Instruments

Description

The FAN4174 (single) and FAN4274 (dual) are voltage feedback amplifiers with CMOS inputs that consume only 200 μ A of supply current per amplifier, while providing ±33 mA of output short-circuit current. These amplifiers are designed to operate 5 V supplies. The common mode voltage range extends beyond the negative and positive rails.

The FAN4174 and FAN4274 are designed on a CMOS process and provide 3.7 MHz of bandwidth and 3 V / μ s of slew rate at a supply voltage of 5 V.

These amplifiers operate and are reliable over a wide temperature range of -40°C to +125°C.

The combination of extended temperature operation, low power, rail-to-rail performance, low-voltage operation, and a tiny package optimize this amplifier family for use in many industrial, general-purpose, and battery-pow ered applications.



Figure 1. Frequency vs. Gain

Part Number	Operating Temperature Range	Package	Packing Method		
FAN4174IS5X	-40 to +125°C	5-Lead SOT23 Package	Tape and Reel (3000)		
FAN4274IMU8X	-40 to +125°C	8-Lead Molded Small-Outline Package	Tape and Reel (3000)		

Typical Application





Pin Configurations



Figure 3. FAN4174 SOT23





FAN4174 Pin Assignments

Pin#	Name	Description
1	OUT	Output
2	-Vs	Negative Supply
3	+IN	Positive Supply
4	-IN	Negative Input
5	+Vs	Positive Supply

FAN4274 Pin Assignments

Pin#	Name	Description
1	OUT1	Output, Channel 1
2	-IN1	Negative Input, Channel 1
3	+IN1	Positive Input, Channel 1
4	-Vs	Negative Supply
5	+IN2	Positive Input, Channel 2
6	-IN2	Negative Input, Channel 2
7	OUT2	Output, Channel 2
8	+Vs	Positive Supply

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Functional operation under any of these conditions is NOT implied. Performance and reliability are guaranteed only if operating conditions are not exceeded.

Symbol	P	Min.	Max.	Unit	
Vcc	Supply Voltage	0	6	V	
Vin	Input Voltage Range			+V _S +0.5	V
TJ	Junction Temperature		+150	°C	
T _{STG}	Storage Temperature	-65	+150	°C	
TL	Lead Soldering, 10 Seconds			+300	°C
0	Thermal Resistance ⁽¹⁾	5-Lead SOT23		256	°C/W
Θja	mermar Resistance	8-Lead MSOP		206	C/ VV

Note:

1. Package thermal resistance JEDEC standard, multi-layer test boards, still air.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Max.	Unit
+Vs	Supply Voltage	2.30	5.25	V
TA	Operating Temperature Range	-40	+125	°C

Electrical Specifications at +2.7 V

 $V_S\!\!=\!\!+2.7~V,~G\!\!=\!\!2,~R_L\!\!=\!\!10~k\Omega$ to $V_S\!/\!2,~R_F\!\!=\!\!5~k\Omega;$ unless otherwise noted.

Symbol	Paramete	r	Conditions	Min.	Тур.	Max.	Units
Frequency I	Domain Response						
UGBW	-3 dB Bandw idth		G=+1		4.0		MHz
BW _{SS}					2.5		MHz
GBWP	Gain Bandwidth Product				4		MHz
Time Domai	in Response						•
t _R , f _F	Rise and Fall Time		V _O =1.0 V Step		300		ns
OS	Overshoot		V _O =1.0 V Step		5		%
SR	Slew Rate		V _O =3 V Step, G=-1		3		V/µs
Distortion a	nd Noise Response		•				
HD2	2nd Harmonic Distortion		V _O =1 V _{PP} , 10 kHz		-66		dBc
HD3	3rd Harmonic Distortion		V _O =1 V _{PP} , 10 kHz		-67		dBc
THD	Total Harmonic Distortion	1	V _O =1 V _{PP} , 10 kHz		0.1		%
en	Input Voltage Noise				26		nV/√Hz
X _{TALK}	Crosstalk (FAN4274)		100 kHz		-100		dB
DC Perform	ance				11		
V _{IO}	Input Offset Voltage ⁽²⁾			-6	0	+6	mV
dV _{IO}	Average Drift				2.1		μV/°C
l _{bn}	Input Bias Current				5		pА
PSRR	Pow er Supply Rejection Ratio ⁽²⁾		DC	50	73		dB
Aol	Open-loop Gain		DC		98		dB
ls	Supply Current per Amplifier ⁽²⁾				200	300	μA
Input Chara	cteristics				11		
RIN	Input Resistance				10		GΩ
CIN	Input Capacitance				1.4		pF
CMIR	Input Common Mode Vo	ltage Range			-0.3 to 2.8		V
	Common Mode Rejection Ratio ⁽²⁾	FAN4174	DC, V _{CM} =0 V to 2.2 V	50	65		D۲
CMRR	Rejection Ratio ⁽²⁾	FAN4274	DC, V _{CM} =0 V to 2.2 V	50	65		dB
Output Cha	racteristics		•				
	Output Voltage Swing ⁽²⁾		RL=10 k Ω to Vs/2	0.03	0.01 to 2.69	2.65	v
Vo			RL=1 k Ω to Vs/2		0.05 to 2.55		v
lsc	Short-Circuit Output Cur	rent			+34/-12		mA
Vs	Pow er Supply Operating	Range			2.5 to 5.5		V

Note:

2. 100% tested at 25°C.

Electrical Specifications at +5 V

 V_S =+5 V, G=2, R_L=10 k Ω to $V_S\!/\!2,$ R_F= 5 k $\!\Omega\!;$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Frequency	Domain Response					
UGBW		G=+1, T _A =85°C		3.7		
UGBW	-3dB Bandwidth	G=+1, T _A =125°C		3.2		- MHz
BWss	1			2.3		MHz
GBWP		T _A =85°C		3.7		
GBWP	Gain Bandwidth Product	T _A =125°C		3.2		MHz
Time Domai	in Response			•		
t _R , f _F	Rise and Fall Time	V _O =1.0 V Step		300		ns
OS	Overshoot	V _O =1.0 V Step		5		%
SR	Slew Rate	V _O =3 V Step, G=-1		3		V/µs
Distortion a	nd Noise Response					
HD2	2nd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-80		dBc
HD3	3rd Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		-80		dBc
THD	Total Harmonic Distortion	V _O =1 V _{PP} , 10 kHz		0.02		%
en	Input Voltage Noise			25		nV/√Hz
XTALK	Crosstalk (FAN4274)	100 kHz		-100		dB
DC Perform	ance			1		
Vio	Input Offset Voltage ⁽³⁾		-8	0	+8	mV
dV _{IO}	Average Drift			2.9		µV/°C
I bn	Input Bias Current			5		pА
PSRR	Pow er Supply Rejection Ratio ⁽³⁾	DC	50	73		dB
AOL	Open-loop Gain	DC		102		dB
ls	Supply Current per Amplifier ⁽³⁾			200	300	μA
Input Chara	cteristics					
R _{IN}	Input Resistance			10		GΩ
CIN	Input Capacitance			1.2		pF
CMIR	Input Common Mode Voltage Range			-0.3 to 5.1		V
CMRR	Common Mode Rejection Ratio ⁽³⁾	DC, V _{CM} =0 V to V _S	58	73		dB
Output Cha	racteristics			1		
Ň		$R_L{=}10~k\Omega$ to $V_S{/}2$	0.03	0.01 to 4.99	4.95	
Vo	Output Voltage Sw ing ⁽³⁾	R _L =1 k Ω to V _S /2		0.1 to 4.9		V
lsc	Short-Circuit Output Current			±33		mA
Vs	Pow er Supply Operating Range			2.5 to 5.5		V

Note:

3. 100% tested at 25°C.



FAN4174 / FAN4274 — Single and Dual, Rail-to-Rail I/O, CMOS Amplifier

100kHz

50kHz

20kHz

<u>10kHz</u>

1.5 1.75 2 2.25 2.5

1k

10k

R **75**Ω

1

111

100k

1M

10k

 $R_L = 1k\Omega$

0 0.5

 $R_L = 10k\Omega$

100k

 $R_L = 200\Omega$

1.5 2



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Application Information

General Description

The FAN4174 amplifier includes single-supply, generalpurpose, voltage-feedback amplifiers, fabricated on a bi-CMOS process. The family features a rail-to-rail input and output and is unity gain stable. The typical noninverting circuit schematic is show n in Figure 21.



Figure 21. Typical Non-inverting Configuration

Input Common Mode Voltage

The common mode input range extends to 300 mV below ground and to 100 mV above V_S in single supply operation. Exceeding these values does not cause phase reversal; how ever, if the input voltage exceeds the rails by more than 0.5 V, the input ESD devices begin to conduct. The output stays at the rail during this overdrive condition. If the absolute maximum input V_{IN} (700 mV beyond either rail) is exceeded, externally limit the input current to ±5 mA, as show n in Figure 22.



Figure 22. Circuit for Input Current Protection

Power Dissipation

The maximum internal power dissipation allowed is directly related to the maximum junction temperature. If the maximum junction temperature exceeds 150°C, performance degradation occurs. If the maximum junction temperature exceeds 150°C for an extended time, device failure may occur.

Overdrive Recovery

Overdrive of an amplifier occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the range is exceeded. The FAN4174 typically recovers in less than 500 ns from an overdrive condition. Figure 23 shows the FAN4174 amplifier in an overdriven condition.



Figure 23. Overdrive Recovery

Driving Capacitive Loads

Figure 9 illustrates the response of the FAN4174 amplifier. A small series resistance (R_S) at the output of the amplifier, illustrated in Figure 24, improves stability and settling performance. R_S values in Figure 9 achieve maximum bandwidth with less than 2 dB of peaking. For maximum flatness, use a larger R_S . Capacitive loads larger than 500 pF require the use of R_S .



Driving a capacitive load introduces phase-lag into the output signal, which reduces phase margin in the amplifier. The unity gain follower is the most sensitive configuration. In a unity gain follower configuration, the FAN4174 amplifier requires a 300Ω series resistor to drive a 100 pF load.

Layout Considerations

General layout and supply bypassing play major roles in high-frequency performance. ON Semiconductor evaluation boards help guide high-frequency layout and aid in device testing and characterization. Follow the steps below as a basis for high-frequency layout:

- 1. Include 6.8 μ F and 0.01 μ F ceramic capacitors.
- 2. Place the 6.8 µF capacitor within 19.05 mm (0.75 inches) of the pow er pin.
- 3. Place the 0.01 µF capacitor within 2.54 mm (0.1 inches) of the power pin.
- 4. Remove the ground plane under and around the part, especially near the input and output pins, to reduce parasitic capacitance.

Minimize all trace lengths to reduce series inductances.

Refer to the evaluation board layouts shown in Figure 27 through Figure 30 for more information.

When evaluating only one channel, complete the following on the unused channel:

- 1. Ground the non-inverting input.
- 2. Short the output to the inverting input.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of this device:

Board	Description	Product
KEB002	Single Channel, Dual Supply, 5 and 6-Lead SOT23	FAN4174IS5X
KEB010	Dual Channel, Dual Supply 8-Lead MSOP	FAN4274IMU8X

Evaluation board schematics are shown in Figure 25 and Figure 26; layouts are shown in Figure 27 through Figure 30.



Figure 25. FAN4174 Evaluation Board Schematic (KEV002)



(KEB010)

Board Layout Information





Figure 31. 5-Lead SOT-23 Package

Package drawings are provided as a service to customers considering ON Semiconductor components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a ON Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of ON Semiconductor's worldwide terms and conditions, specifically the warranty therein, which covers ON Semiconductor products.



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